

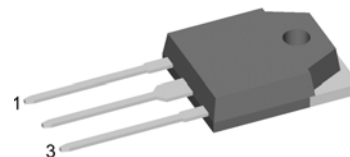
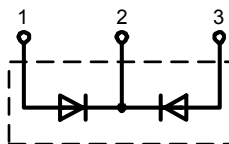
HiPerFRED

High Performance Fast Recovery Diode
Low Loss and Soft Recovery
Common Cathode

$V_{RRM} = 300\text{ V}$
 $I_{FAV} = 2 \times 30\text{ A}$
 $t_{rr} = 35\text{ ns}$

Part number (Marking on product)

DPG 60 C 300QB



Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low I_{RM} -values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low I_{RM} reduces:
 - Power dissipation within the diode
 - Turn-on loss in the commutating switch

Applications:

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

Package:

- TO-3P
- Industry standard outline
 - compatible with TO-247
- Epoxy meets UL 94V-0
- RoHS compliant

Ratings

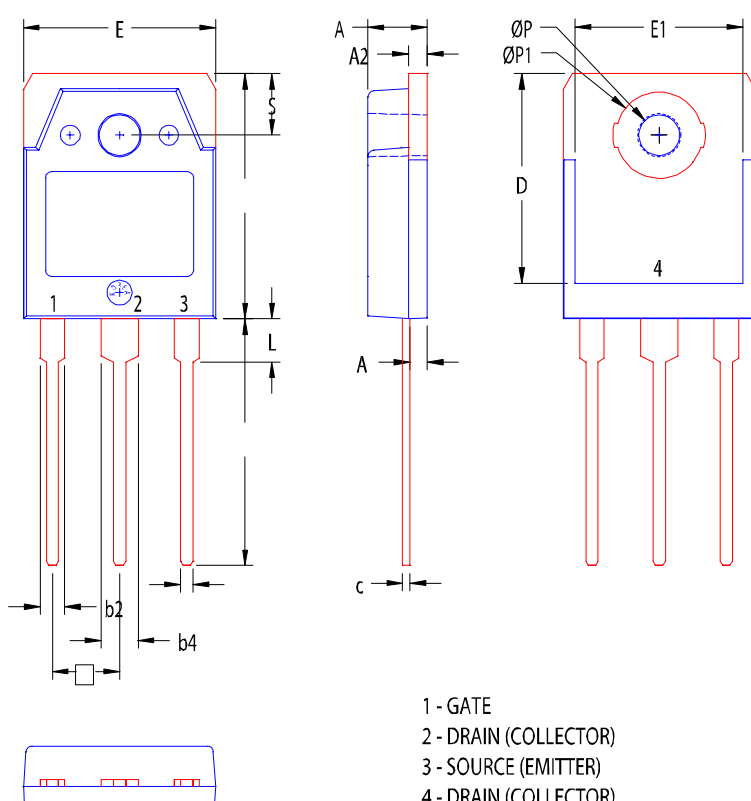
Symbol	Definition	Conditions	min.	typ.	max.	Unit
V_{RRM}	max. repetitive reverse voltage	$T_{VJ} = 25\text{ °C}$			300	V
I_R	reverse current	$V_R = 300\text{ V}$ $T_{VJ} = 25\text{ °C}$ $V_R = 300\text{ V}$ $T_{VJ} = 150\text{ °C}$			1 0.1	μA mA
V_F	forward voltage	$I_F = 30\text{ A}$ $I_F = 60\text{ A}$ $T_{VJ} = 25\text{ °C}$ $I_F = 30\text{ A}$ $I_F = 60\text{ A}$ $T_{VJ} = 150\text{ °C}$			1.34 1.69 1.06 1.39	V V V V
I_{FAV}	average forward current	rectangular, $d = 0.5$ $T_C = 135\text{ °C}$			30	A
V_{FO}	threshold voltage	} for power loss calculation only $T_{VJ} = 175\text{ °C}$			0.70	V
r_F	slope resistance				10.5	m Ω
R_{thJC}	thermal resistance junction to case				0.95	K/W
T_{VJ}	virtual junction temperature		-55		175	°C
P_{tot}	total power dissipation	$T_C = 25\text{ °C}$			160	W
I_{FSM}	max. forward surge current	$t_p = 10\text{ ms (50 Hz), sine}$ $T_{VJ} = 45\text{ °C}$			300	A
I_{RM}	max. reverse recovery current	$I_F = 30\text{ A};$ $-di_F/dt = 200\text{ A}/\mu\text{s}$ $T_{VJ} = 25\text{ °C}$ $T_{VJ} = 125\text{ °C}$		3		A A
t_{rr}	reverse recovery time	$V_R = 100\text{ V}$ $T_{VJ} = 25\text{ °C}$ $T_{VJ} = 125\text{ °C}$		35		ns ns
C_j	junction capacitance	$V_R = 150\text{ V}; f = 1\text{ MHz}$ $T_{VJ} = 25\text{ °C}$		40		pF
E_{AS}	non-repetitive avalanche energy	$I_{AS} = 9\text{ A}; L = 100\text{ }\mu\text{H}$ $T_{VJ} = 25\text{ °C}$			4	mJ
I_{AR}	repetitive avalanche current	$V_A = 1.5 \cdot V_R$ typ.; $f = 10\text{ kHz}$			0.9	A

Symbol	Definition	Conditions	Ratings			Unit
			min.	typ.	max.	
I_{RMS}	RMS current	per pin*			50	A
R_{thCH}	thermal resistance case to heatsink			0.25		K/W
M_D	mounting torque		0.8		1.2	Nm
F_C	mounting force with clip		20		120	N
T_{stg}	storage temperature		-55		150	°C
Weight				5		g

* I_{rms} is typically limited by: 1. pin-to-chip resistance; or by 2. current capability of the chip.

In case of 1, a common cathode/anode configuration and a non-isolated backside, the whole current capability can be used by connecting the backside.

Outlines TO-3P



SYM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	.185	.193	4.70	4.90
A1	.051	.059	1.30	1.50
A2	.057	.065	1.45	1.65
b	.035	.045	0.90	1.15
b2	.075	.087	1.90	2.20
b4	.114	.126	2.90	3.20
c	.022	.031	0.55	0.80
D	.780	.791	19.80	20.10
D1	.665	.677	16.90	17.20
E	.610	.622	15.50	15.80
E1	.531	.539	13.50	13.70
e	.215 BSC		5.45 BSC	
L	.779	.795	19.80	20.20
L1	.134	.142	3.40	3.60
ØP	.126	.134	3.20	3.40
ØP1	.272	.280	6.90	7.10
S	.193	.201	4.90	5.10

All metal area are tin plated.

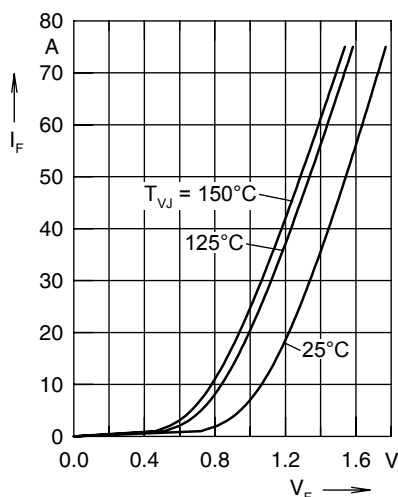


Fig. 1 Forward current I_F vs. V_F

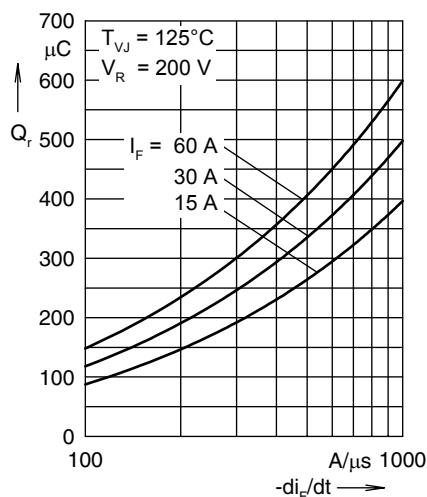


Fig. 2 Typ. reverse recovery charge Q_r versus $-di_F/dt$

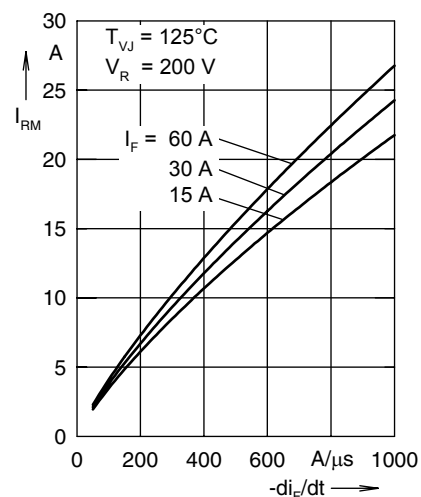


Fig. 3 Typ. peak reverse current I_{RM} versus $-di_F/dt$

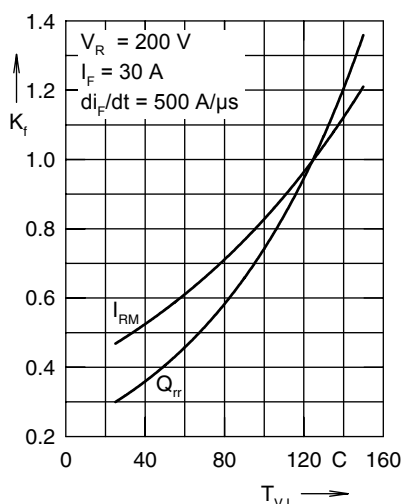


Fig. 4 Dynamic parameters Q_r , I_{RM} versus T_{VJ}

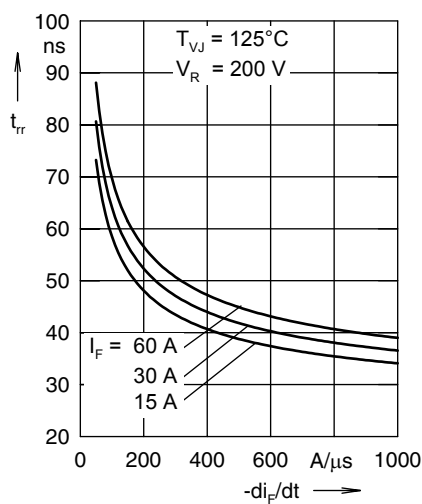


Fig. 5 Typ. recovery time t_{rr} vs. $-di_F/dt$

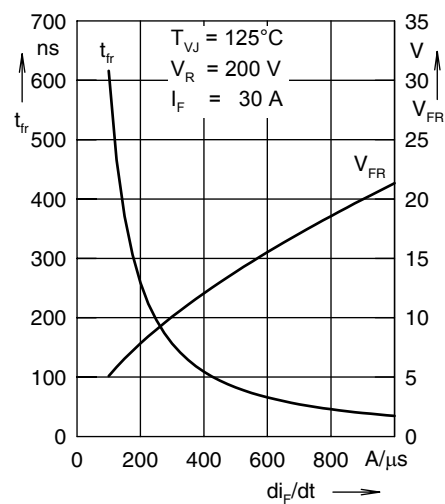


Fig. 6 Typ. peak forward voltage V_{FR} and t_{fr} versus di_F/dt

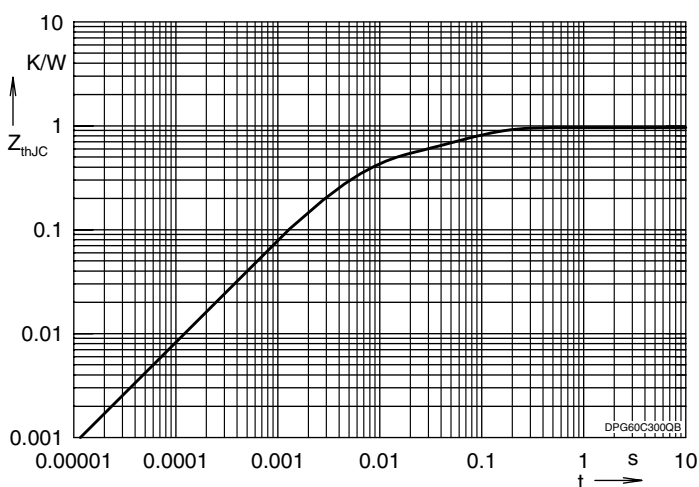


Fig. 7 Transient thermal impedance junction to case

Constants for Z_{thJC} calculation:

i	R_{thi} [K/W]	t_i [s]
1	0.505	0.005
2	0.195	0.0003
3	0.250	0.041